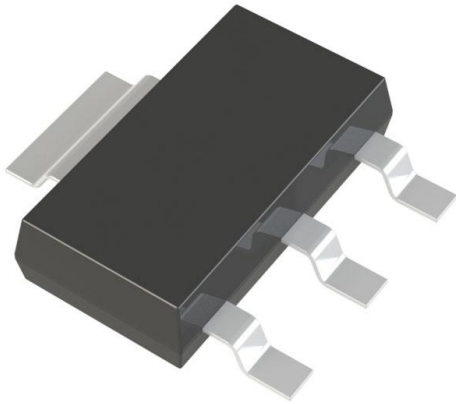


FZT1151ATC Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	FZT1151ATC-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	FZT1151ATC
Description	TRANS PNP 40V 3A SOT223-3
Detailed Description	Bipolar (BJT) Transistor PNP 40 V 3 A 145MHz 2.5 W Surface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

FZT1151ATC

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

40 V

Current - Collector Cutoff (Max):

100nA

Power - Max:

2.5 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

FZT1151A

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

300mV @ 250mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

250 @ 500mA, 2V

Frequency - Transition:

145MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Affected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



FZT1151A

40V PNP MEDIUM POWER TRANSISTOR IN SOT223

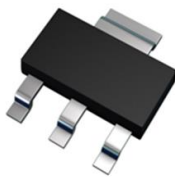
Features

- $BV_{CEO} > -40V$
- $I_C = -3A$ High Continuous Collector Current
- $I_{CM} = -5A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -140mV @ -1A$
- h_{FE} Specified up to -5A for a High Gain Hold-Up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>

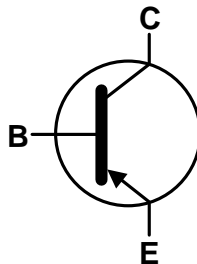
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (G3)
- Weight: 0.112 grams (Approximate)

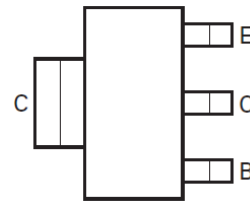
SOT223 (Type DN)



Top View



Device Symbol

Top View
Pin-Out

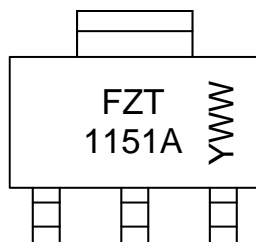
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT1151ATA	AEC-Q101	FZT1151A	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT223 (Type DN)



FZT 1151A = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 0 = 2020)
 WW or $\bar{W}W$ = Week Code (01 to 53)



FZT1151A

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-45	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-3	A
Peak Pulse Current	I _{CM}	-5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	3.0	W	
	(Note 6)	2.0		
	(Note 7)	1.6		
	(Note 8)	1.2		
Thermal Resistance, Junction to Ambient	(Note 5)	41.7	°C/W	
	(Note 6)	62.5		
	(Note 7)	78.1		
	(Note 8)	104		
Thermal Resistance, Junction to Lead	(Note 9)	R _{θJL}	10.9	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

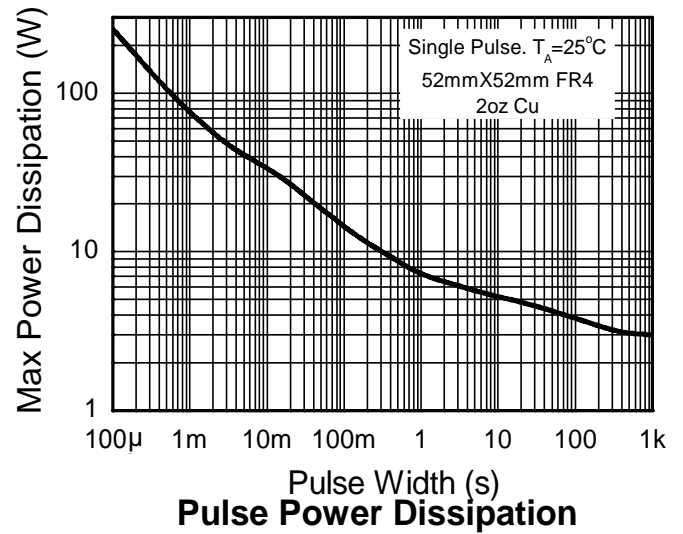
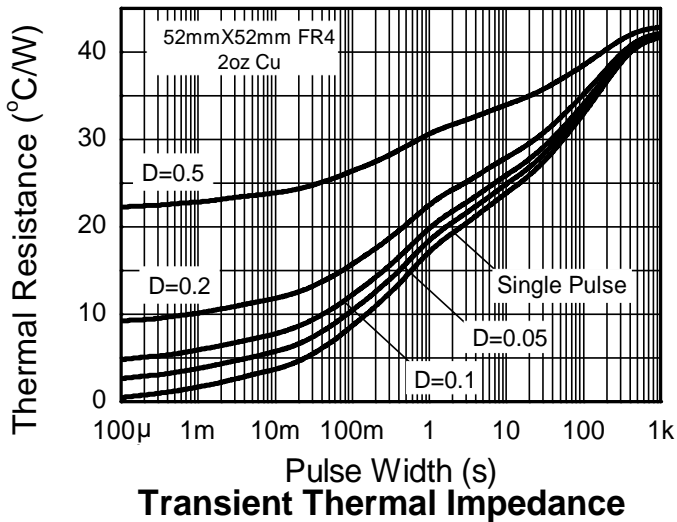
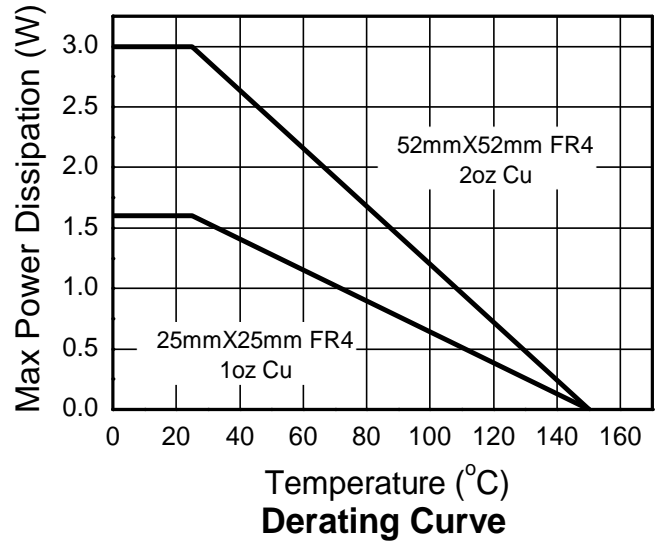
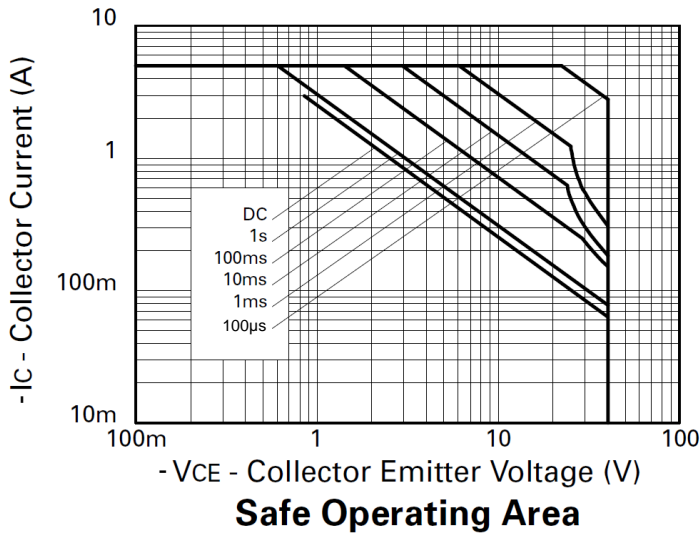
ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 52mm × 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as note (5), except the device is mounted on 25mm × 25mm 2oz copper.
 - Same as note (5), except the device is mounted on 25mm × 25mm 1oz copper.
 - Same as note (5), except the device is mounted on minimum recommended pad layout.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





FZT1151A

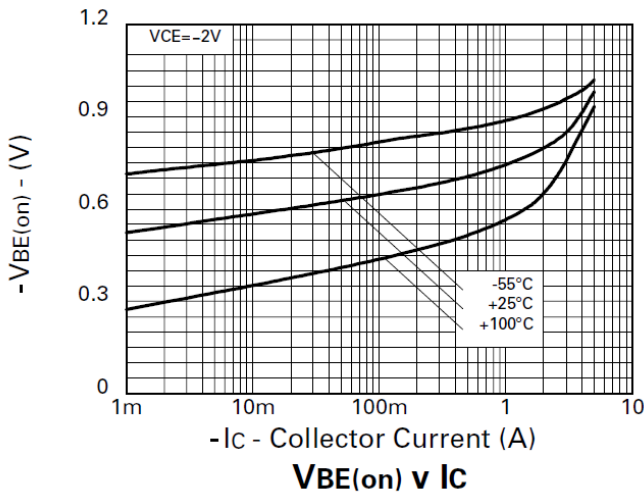
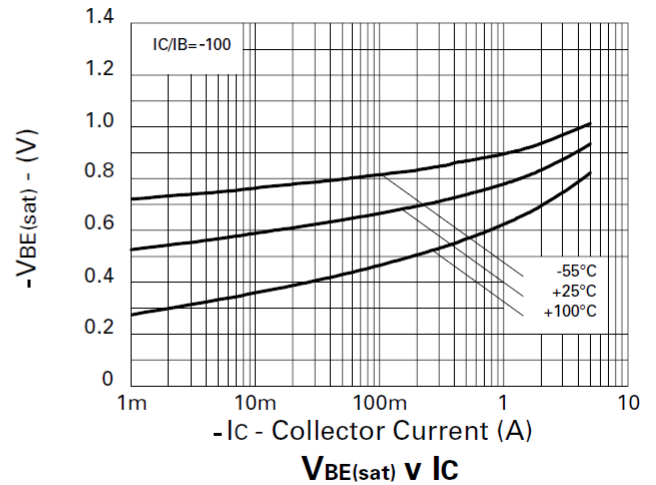
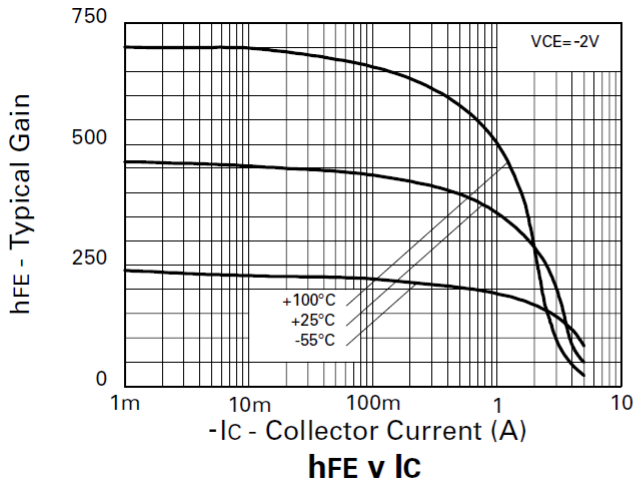
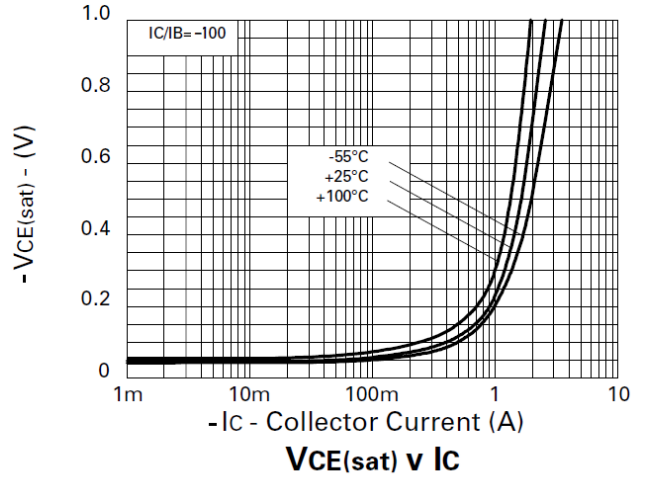
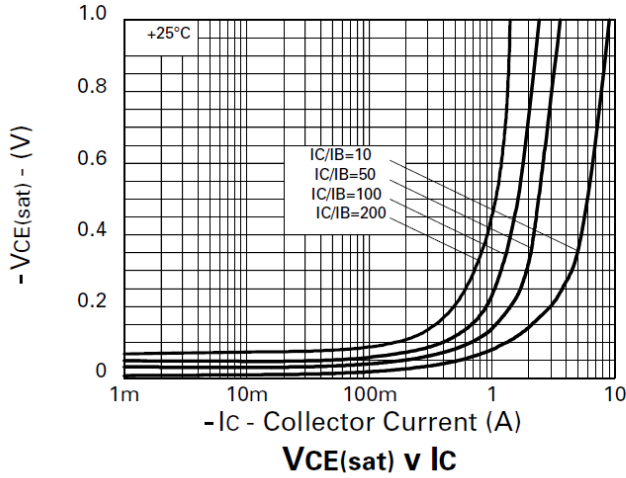
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-45	-95	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CER}	-40	-90	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-40	-85	—	V	I _C = -10mA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEV}	-40	-90	—	V	I _C = -100μA, V _{EB} = +1V
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.5	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	-0.3	-100	nA	V _{CB} = -36V
Emitter Cut-Off Current	I _{EBO}	—	-0.3	-100	nA	V _{EB} = -4V
Collector Emitter Cut-Off Current	I _{CEO}	—	-0.3	-100	nA	V _{CE} = -32V
DC Current Transfer Static Ratio (Note 11)	h _{FE}	270	450	—	—	I _C = -10mA, V _{CE} = -2V
		250	400	800		I _C = -500mA, V _{CE} = -2V
		180	300	—		I _C = -2A, V _{CE} = -2V
		100	190	—		I _C = -3A, V _{CE} = -2V
		—	45	—		I _C = -5A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	—	-60	-90	mV	I _C = -100mA, I _B = -1.0mA
		—	-120	-180		I _C = -500mA, I _B = -5mA
		—	-140	-220		I _C = -1A, I _B = -20mA
		—	-170	-260		I _C = -1.8A, I _B = -70mA
		—	-200	-300		I _C = -3A, I _B = -250mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	—	-985	-1100	mV	I _C = -3A, I _B = -250mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	—	-850	-1000	mV	I _C = -3A, V _{CE} = -2V
Transitional Frequency (Note 11)	f _T	—	145	—	MHz	I _C = -50mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	—	40	—	pF	V _{CB} = -10V, f = 1MHz
Switching Time	t _{on}	—	170	—	ns	V _{CC} = -30V, I _C = -2A, I _B = ±20mA
	t _{off}	—	460	—		

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.



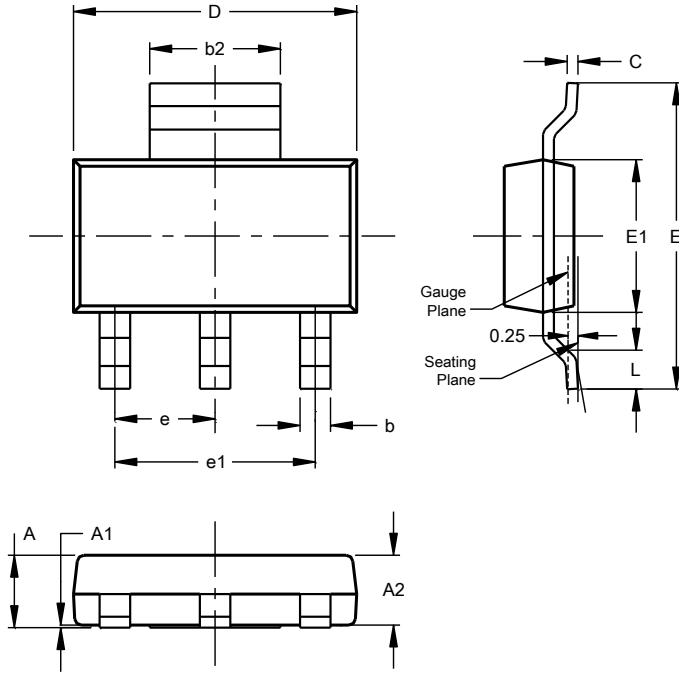
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

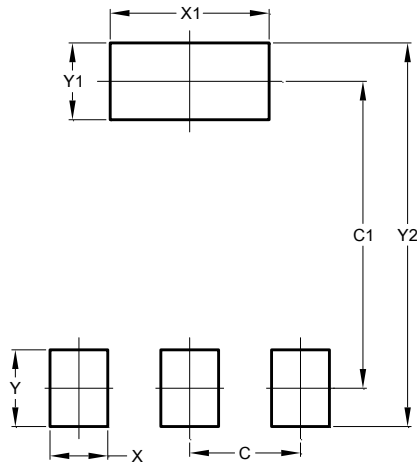


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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